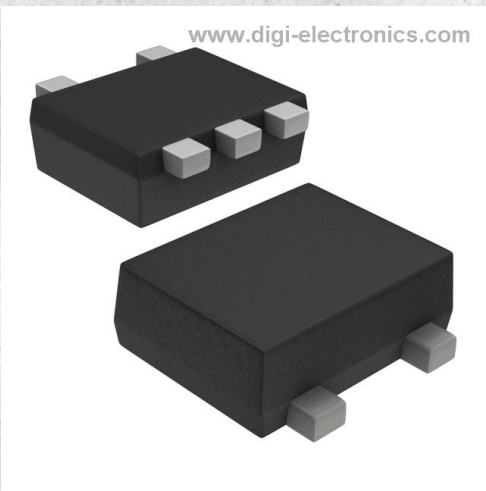
PEMI2STD/RG,115 Datasheet



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DiGi Electronics Part Number	PEMI2STD/RG,115-DG
Manufacturer	NXP USA Inc.
Manufacturer Product Number	PEMI2STD/RG,115
Description	FILTER RC(PI) 100 OHM/11PF SMD
Detailed Description	RC (Pi) EMI Filter 2nd Order Low Pass 2 Channel R = 100Ohms, C = 11pF (Total) SOT-665

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Manufacturer Product Number:	Manufacturer:
PEMI2STD/RG,115	NXP USA Inc.
Series:	Product Status:
PEMI2STD	Obsolete
Type:	Filter Order:
Low Pass	2nd
Technology:	Number of Channels:
RC (Pi)	2
Center / Cutoff Frequency:	Attenuation Value:
-	-
Resistance - Channel (Ohms):	Values:
100	R = 100Ohms, C = 11pF (Total)
ESD Protection:	Operating Temperature:
Yes	-40°C ~ 85°C
Applications:	Voltage - Rated:
Data Lines for Mobile Devices	-
Mounting Type:	Package / Case:
Surface Mount	SOT-665
Size / Dimension:	Height:
0.063" L x 0.047" W (1.60mm x 1.20mm)	0.024" (0.60mm)
Base Product Number:	
PEMI2	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8548.00.0000	

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Team Nexperia

PEMIxQFN; PEMI2STD family

Integrated 1-, 2-, 4-, 6- and 8-channel passive filter network with ESD protection

Rev. 2 — 3 November 2011 Product data sheet

1. Product profile

1.1 General description

The devices are a family of RC low pass filters. They are designed to provide filtering of undesired RF signals on the I/O ports of portable communication or computing devices. The devices incorporate diodes to provide protection to downstream components from ElectroStatic Discharge (ESD) voltages up to ±25 kV.

The devices are fabricated using monolithic silicon technology in lead-free plastic packages.

Table 1. Product overview

Type number	Package	Number of channels	Package pitch (mm)	Package configuration
PEMI1QFN	SOT883	1	-	3-pin MicroPak (QFN compatible)
PEMI2QFN	SOT886	2	0.5	6-pin MicroPak (QFN compatible)
PEMI2STD	SOT665	1	-	5-pin microlead
PEMI4QFN	SOT1157-1	4	0.4	8-pin extremely thin leadless
PEMI6QFN	SOT1158-1	6	0.4	12-pin extremely thin leadless
PEMI8QFN	SOT1159-1	8	0.4	16-pin extremely thin leadless

1.2 Features and benefits

- Pb-free, Restriction of Hazardous Substances (RoHS) compliant and free of halogen and antimony (Dark Green compliant)
- Integrated 1-, 2-, 4-, 6- and 8-channel π-type RC filter network
- ESD protection up to ±25 kV contact discharge according to IEC 61000-4-2, far exceeding level 4

1.3 Applications

General-purpose ElectroMagnetic Interference (EMI) and Radio-Frequency Interference (RFI) filtering and downstream ESD protection for:

- Cellular phone and Personal Communication Systems (PCS) mobile handsets
- Cordless telephones
- Wireless data (WAN/LAN) systems

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Typ	Unit
$R_{s(ch)}$	channel series resistance			
	PEMIxxxx/Cx		20	Ω
	PEMIxxxx/Hx		45	Ω
	PEMIxxxx/Lx		65	Ω
	PEMIxxxx/Rx		100	Ω
	PEMIxxxx/Wx		200	Ω
C_{ch}	channel capacitance	for the total channel; f = 100 kHz; $V_{bias(DC)}$ = 0 V		
	PEMIxxxx/xE		15	pF
	PEMIxxxx/xG		19	pF
	PEMIxxxx/xK		23	pF
	PEMIxxxx/xM		28	pF
	PEMIxxxx/xP		32	pF
	PEMIxxxx/xR		36	pF
	PEMIxxxx/xT		40	pF

2. Pinning information

Table 3. Pinning

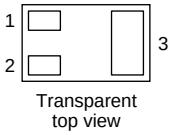
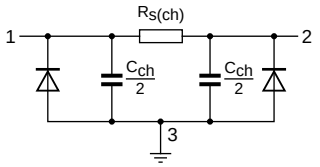
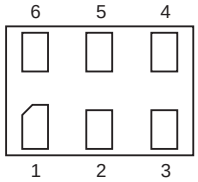
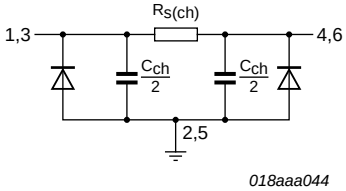
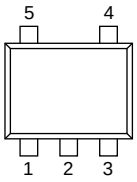
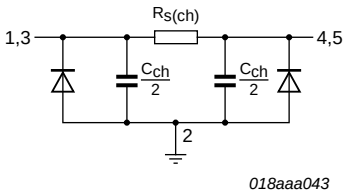
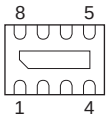
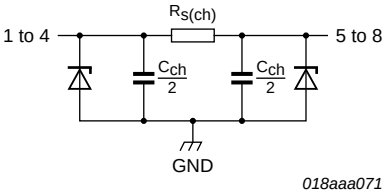
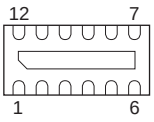
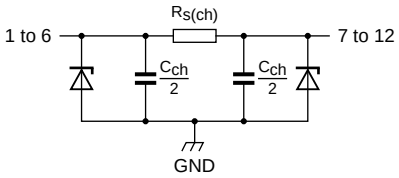
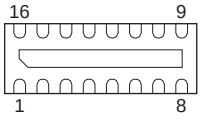
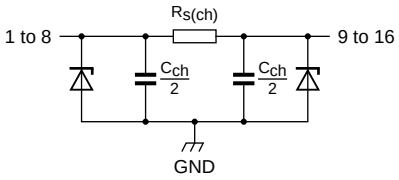
Pin	Description	Simplified outline	Graphic symbol
PEMI1QFN (SOT883)			
1 and 2	filter channel	 Transparent top view	 018aaa042
3	ground (GND)		
PEMI2QFN (SOT886)			
1 and 6	filter channel 1	 Transparent top view	 018aaa044
2 and 5	ground (GND)		
3 and 4	filter channel 2		

Table 3. Pinning *...continued*

Pin	Description	Simplified outline	Graphic symbol
PEMI2STD (SOT665)			
1 and 5	filter channel 1		
2	ground (GND)		
3 and 4	filter channel 2		
PEMI4QFN (SOT1157-1)			
1 and 8	filter channel 1		
2 and 7	filter channel 2		
3 and 6	filter channel 3		
4 and 5	filter channel 4		
ground pad	ground (GND)		
PEMI6QFN (SOT1158-1)			
1 and 12	filter channel 1		
2 and 11	filter channel 2		
3 and 10	filter channel 3		
4 and 9	filter channel 4		
5 and 8	filter channel 5		
6 and 7	filter channel 6		
ground pad	ground (GND)		
PEMI8QFN (SOT1159-1)			
1 and 16	filter channel 1		
2 and 15	filter channel 2		
3 and 14	filter channel 3		
4 and 13	filter channel 4		
5 and 12	filter channel 5		
6 and 11	filter channel 6		
7 and 10	filter channel 7		
8 and 9	filter channel 8		
ground pad	ground (GND)		

3. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
PEMI1QFN	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm	SOT883
PEMI2QFN	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886
PEMI2STD	-	plastic surface-mounted package; 5 leads	SOT665
PEMI4QFN	HXSON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.7 × 0.5 mm	SOT1157-1
PEMI6QFN	HXSON12	plastic thermal enhanced extremely thin small outline package; no leads; 12 terminals; body 1.2 × 2.5 × 0.5 mm	SOT1158-1
PEMI8QFN	HXSON16	plastic thermal enhanced extremely thin small outline package; no leads; 16 terminals; body 1.2 × 3.3 × 0.5 mm	SOT1159-1

4. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		−0.5	+5.6	V
V_{ESD}	electrostatic discharge voltage	IEC 61000-4-2, level 4 all pins to ground			
		contact discharge	-	±15	kV
		air discharge	-	±15	kV
	PEMIxxxx/xM; PEMIxxxx/xP	contact discharge	-	±20	kV
		air discharge	-	±20	kV
	PEMIxxxx/xR; PEMIxxxx/xT	contact discharge	-	±25	kV
		air discharge	-	±25	kV
P_{ch}	channel power dissipation	continuous power; T_{amb} = 85 °C	-	60	mW
P_{tot}	total power dissipation	continuous power; T_{amb} = 85 °C	-	120	mW
T_{stg}	storage temperature		−55	+150	°C
T_{amb}	ambient temperature		−40	+85	°C

5. Characteristics

Table 6. Channel characteristics

T_{amb} = 25 °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{s(ch)}$	channel series resistance					
	PEMIxxxx/Cx		18	20	22	Ω
	PEMIxxxx/Hx		40	45	50	Ω
	PEMIxxxx/Lx		58	65	72	Ω
	PEMIxxxx/Rx		90	100	110	Ω
	PEMIxxxx/Wx		180	200	220	Ω
C_{ch}	channel capacitance	for the total channel; f = 100 kHz				
	PEMIxxxx/xE	$V_{bias(DC)}$ = 0 V	-	15	-	pF
		$V_{bias(DC)}$ = 2.5 V	-	8.5	-	pF
	PEMIxxxx/xG	$V_{bias(DC)}$ = 0 V	-	19	-	pF
		$V_{bias(DC)}$ = 2.5 V	-	11	-	pF
	PEMIxxxx/xK	$V_{bias(DC)}$ = 0 V	-	23	-	pF
		$V_{bias(DC)}$ = 2.5 V	-	13.5	-	pF
	PEMIxxxx/xM	$V_{bias(DC)}$ = 0 V	-	28	-	pF
		$V_{bias(DC)}$ = 2.5 V	-	16	-	pF
	PEMIxxxx/xP	$V_{bias(DC)}$ = 0 V	-	32	-	pF
		$V_{bias(DC)}$ = 2.5 V	-	18.5	-	pF
	PEMIxxxx/xR	$V_{bias(DC)}$ = 0 V	-	36	-	pF
		$V_{bias(DC)}$ = 2.5 V	-	21	-	pF
	PEMIxxxx/xT	$V_{bias(DC)}$ = 0 V	-	40	-	pF
		$V_{bias(DC)}$ = 2.5 V	-	23	-	pF
V_{BR}	breakdown voltage	positive clamp; I_I = 1 mA	5.8	-	9	V
V_F	forward voltage	negative clamp; I_F = 1 mA	−1.5	-	−0.4	V
I_{LR}	reverse leakage current	per channel; V_I = 3.5 V	-	-	0.1	μA

Table 7. Frequency characteristics

T_{amb} = 25 °C; unless otherwise specified; R_{source} = 50 Ω; R_L = 50 Ω.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
α_{il}	insertion loss	C_{ch} = 15 pF				
	PEMIxxxx/CE	$R_{s(ch)}$ = 20 Ω				
		800 MHz < f < 3 GHz	7	-	-	dB
		f = 5 GHz	-	30	-	dB
	PEMIxxxx/HE	$R_{s(ch)}$ = 45 Ω				
		800 MHz < f < 3 GHz	9	-	-	dB
		f = 4 GHz	-	31	-	dB
	PEMIxxxx/LE	$R_{s(ch)}$ = 65 Ω				
		800 MHz < f < 3 GHz	11	-	-	dB
		f = 3.5 GHz	-	32	-	dB
	PEMIxxxx/RE	$R_{s(ch)}$ = 100 Ω				
		800 MHz < f < 3 GHz	13	-	-	dB
		f = 3 GHz	-	33	-	dB
	PEMIxxxx/WE	$R_{s(ch)}$ = 200 Ω				
		800 MHz < f < 3 GHz	18	-	-	dB
		f = 2.2 GHz	-	34	-	dB
α_{il}	insertion loss	C_{ch} = 19 pF				
	PEMIxxxx/CG	$R_{s(ch)}$ = 20 Ω				
		800 MHz < f < 3 GHz	9	-	-	dB
		f = 4 GHz	-	32	-	dB
	PEMIxxxx/HG	$R_{s(ch)}$ = 45 Ω				
		800 MHz < f < 3 GHz	11	-	-	dB
		f = 3.2 GHz	-	33	-	dB
	PEMIxxxx/LG	$R_{s(ch)}$ = 65 Ω				
		800 MHz < f < 3 GHz	13	-	-	dB
		f = 2.8 GHz	-	33.5	-	dB
	PEMIxxxx/RG	$R_{s(ch)}$ = 100 Ω				
		800 MHz < f < 3 GHz	15	-	-	dB
		f = 2.5 GHz	-	34	-	dB
	PEMIxxxx/WG	$R_{s(ch)}$ = 200 Ω				
		800 MHz < f < 3 GHz	21	-	-	dB
		f = 1.9 GHz	-	35.5	-	dB

Table 7. Frequency characteristics *...continued*

T_{amb} = 25 °C; unless otherwise specified; R_{source} = 50 Ω; R_L = 50 Ω.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
α_{il}	insertion loss	C_{ch} = 23 pF				
	PEMIxxxx/CK	$R_{s(ch)}$ = 20 Ω				
		800 MHz < f < 3 GHz	10	-	-	dB
		f = 3.6 GHz	-	33	-	dB
	PEMIxxxx/HK	$R_{s(ch)}$ = 45 Ω				
		800 MHz < f < 3 GHz	13	-	-	dB
		f = 2.8 GHz	-	34	-	dB
	PEMIxxxx/LK	$R_{s(ch)}$ = 65 Ω				
		800 MHz < f < 3 GHz	15	-	-	dB
		f = 2.5 GHz	-	35	-	dB
	PEMIxxxx/RK	$R_{s(ch)}$ = 100 Ω				
		800 MHz < f < 3 GHz	18	-	-	dB
		f = 2.1 GHz	-	36	-	dB
	PEMIxxxx/WK	$R_{s(ch)}$ = 200 Ω				
		800 MHz < f < 3 GHz	24	-	-	dB
		f = 1.6 GHz	-	37	-	dB
α_{il}	insertion loss	C_{ch} = 28 pF				
	PEMIxxxx/CM	$R_{s(ch)}$ = 20 Ω				
		800 MHz < f < 3 GHz	12	-	-	dB
		f = 3.2 GHz	-	34	-	dB
	PEMIxxxx/HM	$R_{s(ch)}$ = 45 Ω				
		800 MHz < f < 3 GHz	15	-	-	dB
		f = 2.5 GHz	-	35	-	dB
	PEMIxxxx/LM	$R_{s(ch)}$ = 65 Ω				
		800 MHz < f < 3 GHz	17	-	-	dB
		f = 2.1 GHz	-	36	-	dB
	PEMIxxxx/RM	$R_{s(ch)}$ = 100 Ω				
		800 MHz < f < 3 GHz	21	-	-	dB
		f = 1.8 GHz	-	37	-	dB
	PEMIxxxx/WM	$R_{s(ch)}$ = 200 Ω				
		800 MHz < f < 3 GHz	27	-	-	dB
		f = 1.4 GHz	-	38	-	dB

Table 7. Frequency characteristics *...continued*

T_{amb} = 25 °C; unless otherwise specified; R_{source} = 50 Ω; R_L = 50 Ω.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
α_{il}	insertion loss	C_{ch} = 32 pF				
	PEMIxxxx/CP	$R_{s(ch)}$ = 20 Ω				
		800 MHz < f < 3 GHz	13	-	-	dB
		f = 2.9 GHz	-	36	-	dB
	PEMIxxxx/HP	$R_{s(ch)}$ = 45 Ω				
		800 MHz < f < 3 GHz	17	-	-	dB
		f = 2.2 GHz	-	36	-	dB
	PEMIxxxx/LP	$R_{s(ch)}$ = 65 Ω				
		800 MHz < f < 3 GHz	19	-	-	dB
		f = 1.9 GHz	-	37	-	dB
	PEMIxxxx/RP	$R_{s(ch)}$ = 100 Ω				
		800 MHz < f < 3 GHz	23	-	-	dB
		f = 1.6 GHz	-	38	-	dB
	PEMIxxxx/WP	$R_{s(ch)}$ = 200 Ω				
		800 MHz < f < 3 GHz	30	-	-	dB
		f = 1.2 GHz	-	39	-	dB
α_{il}	insertion loss	C_{ch} = 36 pF				
	PEMIxxxx/CR	$R_{s(ch)}$ = 20 Ω				
		800 MHz < f < 3 GHz	14	-	-	dB
		f = 2.6 GHz	-	36	-	dB
	PEMIxxxx/HR	$R_{s(ch)}$ = 45 Ω				
		800 MHz < f < 3 GHz	18	-	-	dB
		f = 2.0 GHz	-	37	-	dB
	PEMIxxxx/LR	$R_{s(ch)}$ = 65 Ω				
		800 MHz < f < 3 GHz	21	-	-	dB
		f = 1.8 GHz	-	38	-	dB
	PEMIxxxx/RR	$R_{s(ch)}$ = 100 Ω				
		800 MHz < f < 3 GHz	25	-	-	dB
		f = 1.6 GHz	-	39	-	dB
	PEMIxxxx/WR	$R_{s(ch)}$ = 200 Ω				
		800 MHz < f < 3 GHz	32	-	-	dB
		f = 1.2 GHz	-	40	-	dB

Table 7. Frequency characteristics *...continued*

T_{amb} = 25 °C; unless otherwise specified; R_{source} = 50 Ω; R_L = 50 Ω.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
α_{il}	insertion loss	C_{ch} = 40 pF				
	PEMIxxxx/CT	$R_{s(ch)}$ = 20 Ω				
		800 MHz < f < 3 GHz	16	-	-	dB
		f = 2.5 GHz	-	36	-	dB
	PEMIxxxx/HT	$R_{s(ch)}$ = 45 Ω				
		800 MHz < f < 3 GHz	20	-	-	dB
		f = 1.9 GHz	-	38	-	dB
	PEMIxxxx/LT	$R_{s(ch)}$ = 65 Ω				
		800 MHz < f < 3 GHz	23	-	-	dB
		f = 1.6 GHz	-	39	-	dB
	PEMIxxxx/RT	$R_{s(ch)}$ = 100 Ω				
		800 MHz < f < 3 GHz	27	-	-	dB
		f = 1.4 GHz	-	40	-	dB
	PEMIxxxx/WT	$R_{s(ch)}$ = 200 Ω				
		800 MHz < f < 3 GHz	32	-	-	dB
		f = 1.0 GHz	-	41	-	dB

6. Application information

6.1 Use cases

The selection of one of the filter devices has to be performed in dependence of the maximum clock frequency, the driver strength, the capacitive load of the sink and the maximum applicable rise and fall times.

6.2 LCD interfaces, medium-speed interfaces

For digital interfaces such as Liquid Crystal Display (LCD) interfaces running at clock speeds between 10 MHz and 25 MHz or more, the devices can be used in dependence of the sink load, the clock speed, the driver strength and the rise and fall time requirements. The minimum EMI filter requirements may be an important factor, too.

6.3 Keypad, low-speed interfaces

Especially for lower-speed interfaces such as keypads, low-speed serial interfaces and low-speed control signals, the devices offer a very robust ESD protection and strong suppression of unwanted frequencies (EMI filtering). Due to their small size the devices can easily be spread on a Printed-Circuit Board (PCB) in order to move the ESD and EMI protection close to the part of the design which shall be protected.

6.4 Insertion loss

The devices are designed as EMI/RFI filters for multichannel interfaces.

All measurements were performed in a typical 50 Ω NetWork Analyzer (NWA) setup as shown in Figure 1. The insertion loss was measured with a test Printed-Circuit Board (PCB) utilizing laser-drilled micro-via holes which connect the PCB ground plane to the devices ground pins.

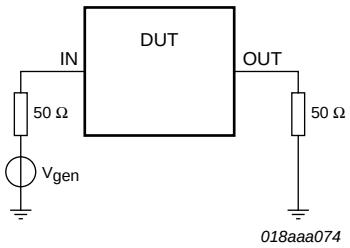
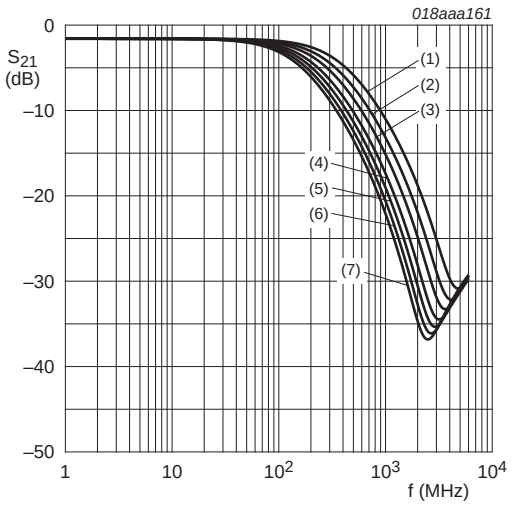


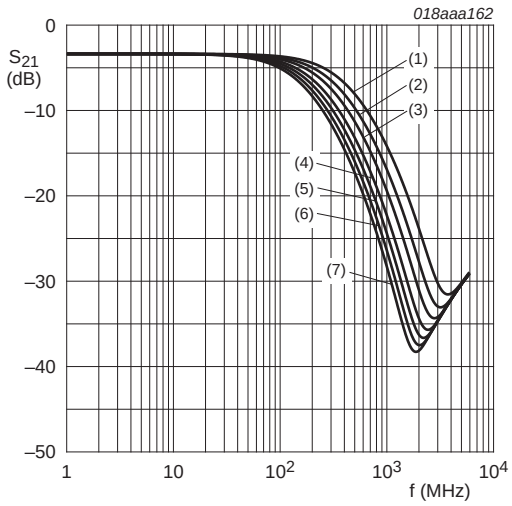
Fig 1. Frequency response setup



$R_{s(ch)}$ = 20 Ω

(1) PEMIxxxx/CE
(2) PEMIxxxx/CG
(3) PEMIxxxx/CK
(4) PEMIxxxx/CM
(5) PEMIxxxx/CP
(6) PEMIxxxx/CR
(7) PEMIxxxx/CT

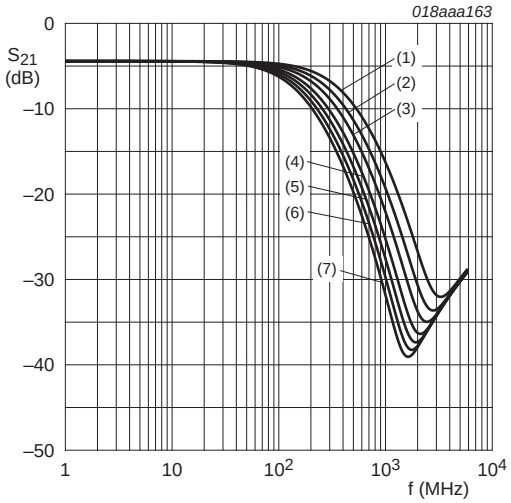
Fig 2. PEMIxxxx/Cx: Frequency response curves



$R_{s(ch)}$ = 45 Ω

(1) PEMIxxxx/HE
(2) PEMIxxxx/HG
(3) PEMIxxxx/HK
(4) PEMIxxxx/HM
(5) PEMIxxxx/HP
(6) PEMIxxxx/HR
(7) PEMIxxxx/HT

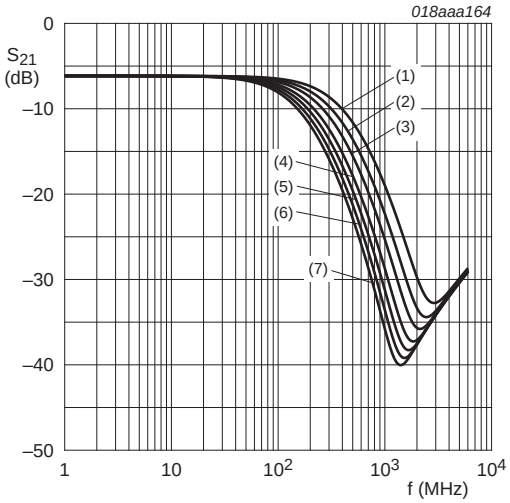
Fig 3. PEMIxxxx/Hx: Frequency response curves



$R_{s(ch)}$ = 65 Ω

(1) PEMIxxxx/LE
(2) PEMIxxxx/LG
(3) PEMIxxxx/LK
(4) PEMIxxxx/LM
(5) PEMIxxxx/LP
(6) PEMIxxxx/LR
(7) PEMIxxxx/LT

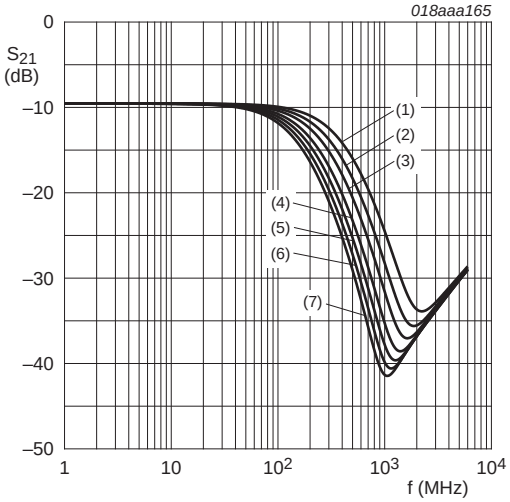
Fig 4. PEMIxxxx/Lx: Frequency response curves



$R_{s(ch)}$ = 100 Ω

(1) PEMIxxxx/RE
(2) PEMIxxxx/RG
(3) PEMIxxxx/RK
(4) PEMIxxxx/RM
(5) PEMIxxxx/RP
(6) PEMIxxxx/RR
(7) PEMIxxxx/RT

Fig 5. PEMIxxxx/Rx: Frequency response curves



$R_{s(ch)}$ = 200 Ω

(1) PEMIxxxx/WE
(2) PEMIxxxx/WG
(3) PEMIxxxx/WK
(4) PEMIxxxx/WM
(5) PEMIxxxx/WP
(6) PEMIxxxx/WR
(7) PEMIxxxx/WT

Fig 6. PEMIxxxx/Wx: Frequency response curves

All important values of the RF behavior such as relative –3dB frequency, insertion loss at 800 MHz and above and also the DC attenuation in an NWA environment can be derived from the insertion loss response curves depicted in Figure 2 to 6.

Note: insertion loss at low frequencies (1 MHz) is nearly independent from the channel capacitance values available within the PEMI family.

6.4.1 Relative –3dB frequency (π-filter structure)

Table 8. Relative –3dB frequency (MHz) per RC combination; typical values

T_{amb} = 25 °C; unless otherwise specified.

PEMIxxxx/		**xE**	**xG**	**xK**	**xM**	**xP**	**xR**	**xT**
C_{ch} (pF)		**15**	**19**	**23**	**28**	**32**	**36**	**40**
PEMIxxxx/	**$R_{s(ch)}$**							
Cx	20	397 MHz	317 MHz	264 MHz	218 MHz	194 MHz	170 MHz	153 MHz
Hx	45	376 MHz	300 MHz	249 MHz	206 MHz	185 MHz	161 MHz	145 MHz
Lx	65	361 MHz	288 MHz	239 MHz	197 MHz	176 MHz	155 MHz	139 MHz
Rx	100	343 MHz	272 MHz	227 MHz	187 MHz	166 MHz	145 MHz	131 MHz
Wx	200	311 MHz	247 MHz	205 MHz	169 MHz	150 MHz	132 MHz	119 MHz

6.4.2 Insertion loss (dB) at 800 MHz (π-filter structure)

Table 9. Insertion loss (dB) at 800 MHz per RC combination; typical values

T_{amb} = 25 °C; unless otherwise specified.

PEMIxxxx/		xE	xG	xK	xM	xP	xR	xT
C_{ch} (pF)		15	19	23	28	32	36	40
PEMIxxxx/	$R_{s(ch)}$							
Cx	20	−9 dB	−11 dB	−13 dB	−15 dB	−16 dB	−18 dB	−19 dB
Hx	45	−12 dB	−14 dB	−17 dB	−19 dB	−21 dB	−23 dB	−25 dB
Lx	65	−14 dB	−17 dB	−19 dB	−22 dB	−25 dB	−27 dB	−29 dB
Rx	100	−17 dB	−20 dB	−23 dB	−26 dB	−29 dB	−32 dB	−35 dB
Wx	200	−22 dB	−26 dB	−29 dB	−34 dB	−36 dB	−39 dB	−41 dB

6.4.3 Insertion loss (dB) at frequencies lower than 1 MHz (π-filter structure)

Table 10. Insertion loss (dB) at ≤ 1 MHz per RC combination; typical values

T_{amb} = 25 °C; unless otherwise specified.

PEMIxxxx/		xE	xG	xK	xM	xP	xR	xT
C_{ch} (pF)		15	19	23	28	32	36	40
PEMIxxxx/	$R_{s(ch)}$							
Cx	20	−1.6 dB	−1.6 dB	−1.6 dB	−1.6 dB	−1.6 dB	−1.6 dB	−1.6 dB
Hx	45	−3.2 dB	−3.2 dB	−3.2 dB	−3.2 dB	−3.2 dB	−3.2 dB	−3.2 dB
Lx	65	−4.3 dB	−4.3 dB	−4.3 dB	−4.3 dB	−4.3 dB	−4.3 dB	−4.3 dB
Rx	100	−6.0 dB	−6.0 dB	−6.0 dB	−6.0 dB	−6.0 dB	−6.0 dB	−6.0 dB
Wx	200	−9.5 dB	−9.5 dB	−9.5 dB	−9.5 dB	−9.5 dB	−9.5 dB	−9.5 dB

7. Marking

Table 11. Marking codes

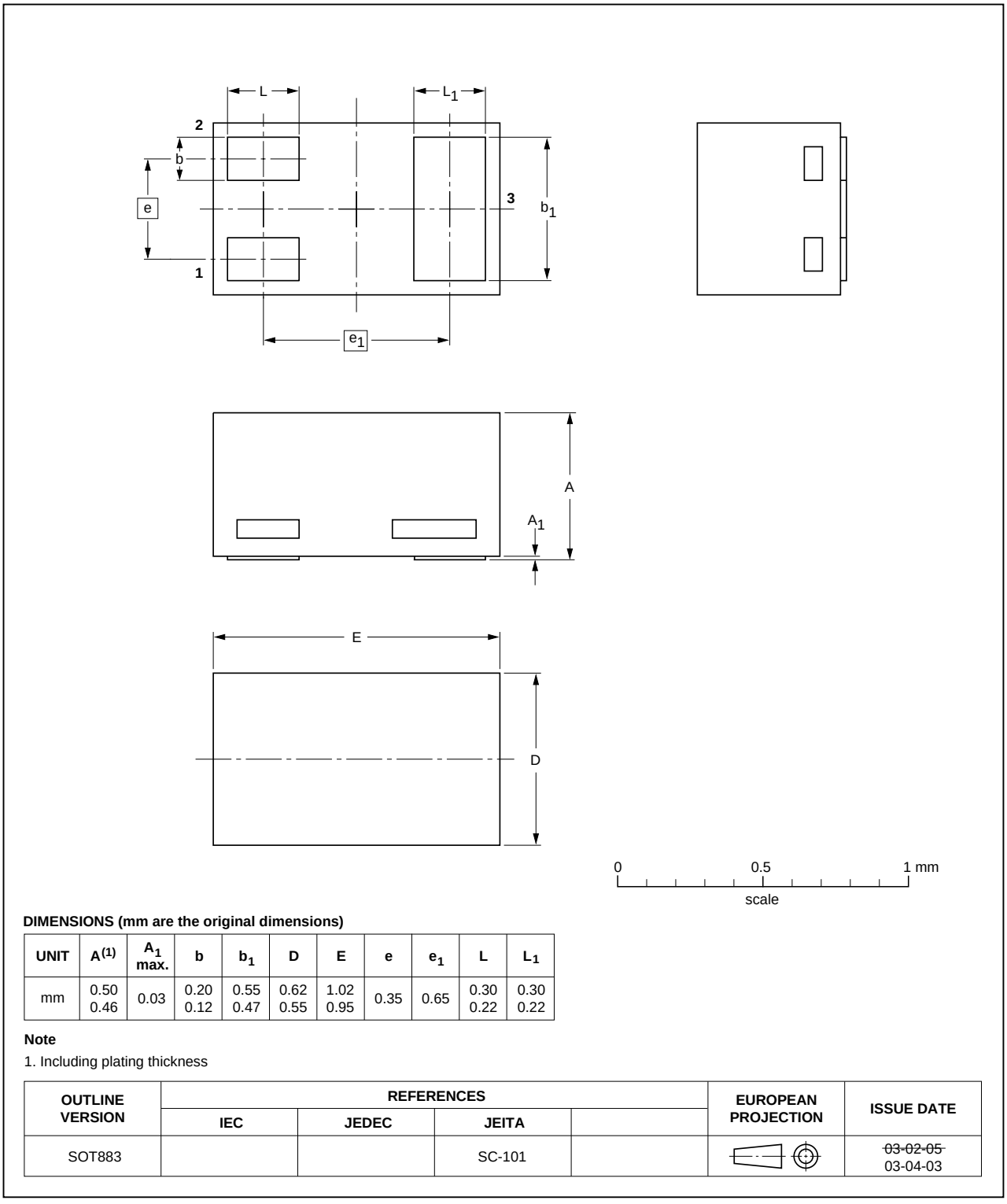
Type number	Marking code	Type number	Marking code	Type number	Marking code	Type number	Marking code
PEMI1QFN/CE	CE	PEMI2QFN/LP	LP	PEMI4QFN/CE	CE	PEMI6QFN/LP	LP
PEMI1QFN/CG	CG	PEMI2QFN/LR	LR	PEMI4QFN/CG	CG	PEMI6QFN/LR	LR
PEMI1QFN/CK	CK	PEMI2QFN/LT	LT	PEMI4QFN/CK	CK	PEMI6QFN/LT	LT
PEMI1QFN/CM	CM	PEMI2QFN/RE	RE	PEMI4QFN/CM	CM	PEMI6QFN/RE	RE
PEMI1QFN/CP	CP	PEMI2QFN/RG	RG	PEMI4QFN/CP	CP	PEMI6QFN/RG	RG
PEMI1QFN/CR	CR	PEMI2QFN/RK	RK	PEMI4QFN/CR	CR	PEMI6QFN/RK	RK
PEMI1QFN/CT	CT	PEMI2QFN/RM	RM	PEMI4QFN/CT	CT	PEMI6QFN/RM	RM
PEMI1QFN/HE	HE	PEMI2QFN/RP	RP	PEMI4QFN/HE	HE	PEMI6QFN/RP	RP
PEMI1QFN/HG	HG	PEMI2QFN/RR	RR	PEMI4QFN/HG	HG	PEMI6QFN/RR	RR
PEMI1QFN/HK	HK	PEMI2QFN/RT	RT	PEMI4QFN/HK	HK	PEMI6QFN/RT	RT
PEMI1QFN/HM	HM	PEMI2QFN/WE	WE	PEMI4QFN/HM	HM	PEMI6QFN/WE	WE
PEMI1QFN/HP	HP	PEMI2QFN/WG	WG	PEMI4QFN/HP	HP	PEMI6QFN/WG	WG
PEMI1QFN/HR	HR	PEMI2QFN/WK	WK	PEMI4QFN/HR	HR	PEMI6QFN/WK	WK
PEMI1QFN/HT	HT	PEMI2QFN/WM	WM	PEMI4QFN/HT	HT	PEMI6QFN/WM	WM

Table 11. Marking codes *...continued*

Type number	Marking code	Type number	Marking code	Type number	Marking code	Type number	Marking code
PEMI1QFN/LE	LE	PEMI2QFN/WP	WP	PEMI4QFN/LE	LE	PEMI6QFN/WP	WP
PEMI1QFN/LG	LG	PEMI2QFN/WR	WR	PEMI4QFN/LG	LG	PEMI6QFN/WR	WR
PEMI1QFN/LK	LK	PEMI2QFN/WT	WT	PEMI4QFN/LK	LK	PEMI6QFN/WT	WT
PEMI1QFN/LM	LM	PEMI2STD/CE	CE	PEMI4QFN/LM	LM	PEMI8QFN/CE	CE
PEMI1QFN/LP	LP	PEMI2STD/CG	CG	PEMI4QFN/LP	LP	PEMI8QFN/CG	CG
PEMI1QFN/LR	LR	PEMI2STD/CK	CK	PEMI4QFN/LR	LR	PEMI8QFN/CK	CK
PEMI1QFN/LT	LT	PEMI2STD/CM	CM	PEMI4QFN/LT	LT	PEMI8QFN/CM	CM
PEMI1QFN/RE	RE	PEMI2STD/CP	CP	PEMI4QFN/RE	RE	PEMI8QFN/CP	CP
PEMI1QFN/RG	RG	PEMI2STD/CR	CR	PEMI4QFN/RG	RG	PEMI8QFN/CR	CR
PEMI1QFN/RK	RK	PEMI2STD/CT	CT	PEMI4QFN/RK	RK	PEMI8QFN/CT	CT
PEMI1QFN/RM	RM	PEMI2STD/HE	HE	PEMI4QFN/RM	RM	PEMI8QFN/HE	HE
PEMI1QFN/RP	RP	PEMI2STD/HG	HG	PEMI4QFN/RP	RP	PEMI8QFN/HG	HG
PEMI1QFN/RR	RR	PEMI2STD/HK	HK	PEMI4QFN/RR	RR	PEMI8QFN/HK	HK
PEMI1QFN/RT	RT	PEMI2STD/HM	HM	PEMI4QFN/RT	RT	PEMI8QFN/HM	HM
PEMI1QFN/WE	WE	PEMI2STD/HP	HP	PEMI4QFN/WE	WE	PEMI8QFN/HP	HP
PEMI1QFN/WG	WG	PEMI2STD/HR	HR	PEMI4QFN/WG	WG	PEMI8QFN/HR	HR
PEMI1QFN/WK	WK	PEMI2STD/HT	HT	PEMI4QFN/WK	WK	PEMI8QFN/HT	HT
PEMI1QFN/WM	WM	PEMI2STD/LE	LE	PEMI4QFN/WM	WM	PEMI8QFN/LE	LE
PEMI1QFN/WP	WP	PEMI2STD/LG	LG	PEMI4QFN/WP	WP	PEMI8QFN/LG	LG
PEMI1QFN/WR	WR	PEMI2STD/LK	LK	PEMI4QFN/WR	WR	PEMI8QFN/LK	LK
PEMI1QFN/WT	WT	PEMI2STD/LM	LM	PEMI4QFN/WT	WT	PEMI8QFN/LM	LM
PEMI2QFN/CE	CE	PEMI2STD/LP	LP	PEMI6QFN/CE	CE	PEMI8QFN/LP	LP
PEMI2QFN/CG	CG	PEMI2STD/LR	LR	PEMI6QFN/CG	CG	PEMI8QFN/LR	LR
PEMI2QFN/CK	CK	PEMI2STD/LT	LT	PEMI6QFN/CK	CK	PEMI8QFN/LT	LT
PEMI2QFN/CM	CM	PEMI2STD/RE	RE	PEMI6QFN/CM	CM	PEMI8QFN/RE	RE
PEMI2QFN/CP	CP	PEMI2STD/RG	RG	PEMI6QFN/CP	CP	PEMI8QFN/RG	RG
PEMI2QFN/CR	CR	PEMI2STD/RK	RK	PEMI6QFN/CR	CR	PEMI8QFN/RK	RK
PEMI2QFN/CT	CT	PEMI2STD/RM	RM	PEMI6QFN/CT	CT	PEMI8QFN/RM	RM
PEMI2QFN/HE	HE	PEMI2STD/RP	RP	PEMI6QFN/HE	HE	PEMI8QFN/RP	RP
PEMI2QFN/HG	HG	PEMI2STD/RR	RR	PEMI6QFN/HG	HG	PEMI8QFN/RR	RR
PEMI2QFN/HK	HK	PEMI2STD/RT	RT	PEMI6QFN/HK	HK	PEMI8QFN/RT	RT
PEMI2QFN/HM	HM	PEMI2STD/WE	WE	PEMI6QFN/HM	HM	PEMI8QFN/WE	WE
PEMI2QFN/HP	HP	PEMI2STD/WG	WG	PEMI6QFN/HP	HP	PEMI8QFN/WG	WG
PEMI2QFN/HR	HR	PEMI2STD/WK	WK	PEMI6QFN/HR	HR	PEMI8QFN/WK	WK
PEMI2QFN/HT	HT	PEMI2STD/WM	WM	PEMI6QFN/HT	HT	PEMI8QFN/WM	WM
PEMI2QFN/LE	LE	PEMI2STD/WP	WP	PEMI6QFN/LE	LE	PEMI8QFN/WP	WP
PEMI2QFN/LG	LG	PEMI2STD/WR	WR	PEMI6QFN/LG	LG	PEMI8QFN/WR	WR
PEMI2QFN/LK	LK	PEMI2STD/WT	WT	PEMI6QFN/LK	LK	PEMI8QFN/WT	WT
PEMI2QFN/LM	LM	-	-	PEMI6QFN/LM	LM	-	-

8. Package outline

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm **SOT883**



DIMENSIONS (mm are the original dimensions)

UNIT	A(1)	A_1 max.	b	b_1	D	E	e	e_1	L	L_1
mm	0.50 0.46	0.03	0.20 0.12	0.55 0.47	0.62 0.55	1.02 0.95	0.35	0.65	0.30 0.22	0.30 0.22

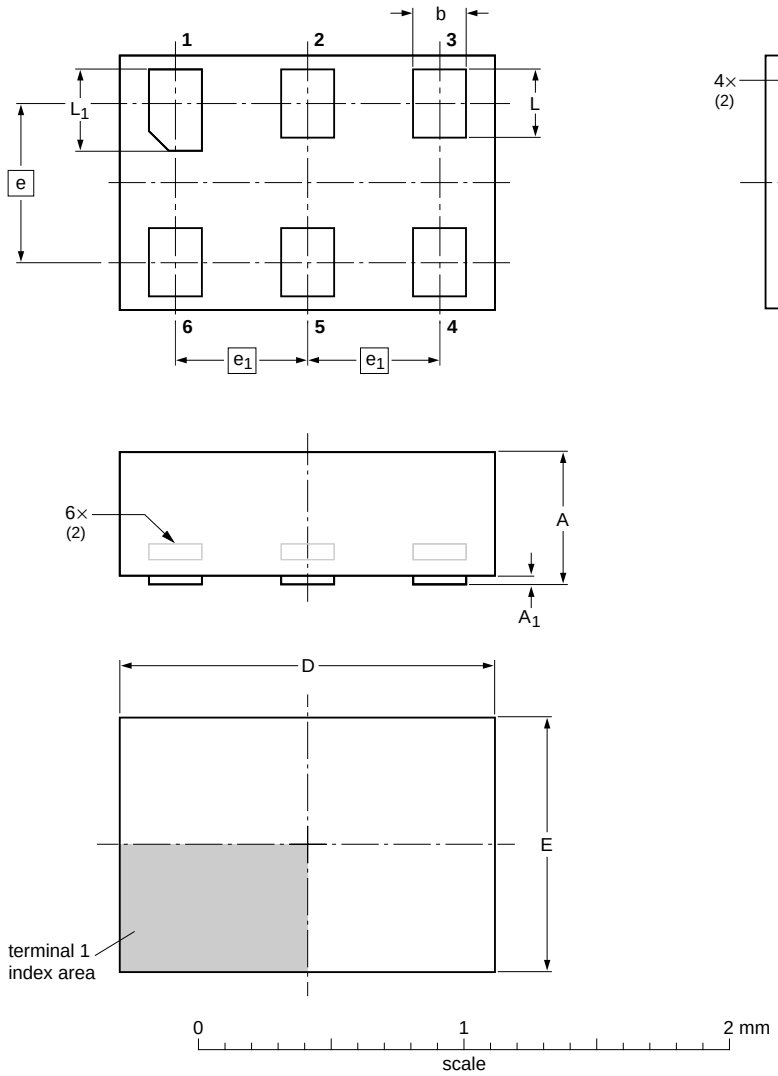
Note

1. Including plating thickness

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT883			SC-101			~~03-02-05~~ 03-04-03

Fig 7. Package outline PEMI1QFN (SOT883/SC-101)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm **SOT886**



DIMENSIONS (mm are the original dimensions)

UNIT	A(1) max	A_1 max	b	D	E	e	e_1	L	L_1
mm	0.5	0.04	0.25 0.17	1.5 1.4	1.05 0.95	0.6	0.5	0.35 0.27	0.40 0.32

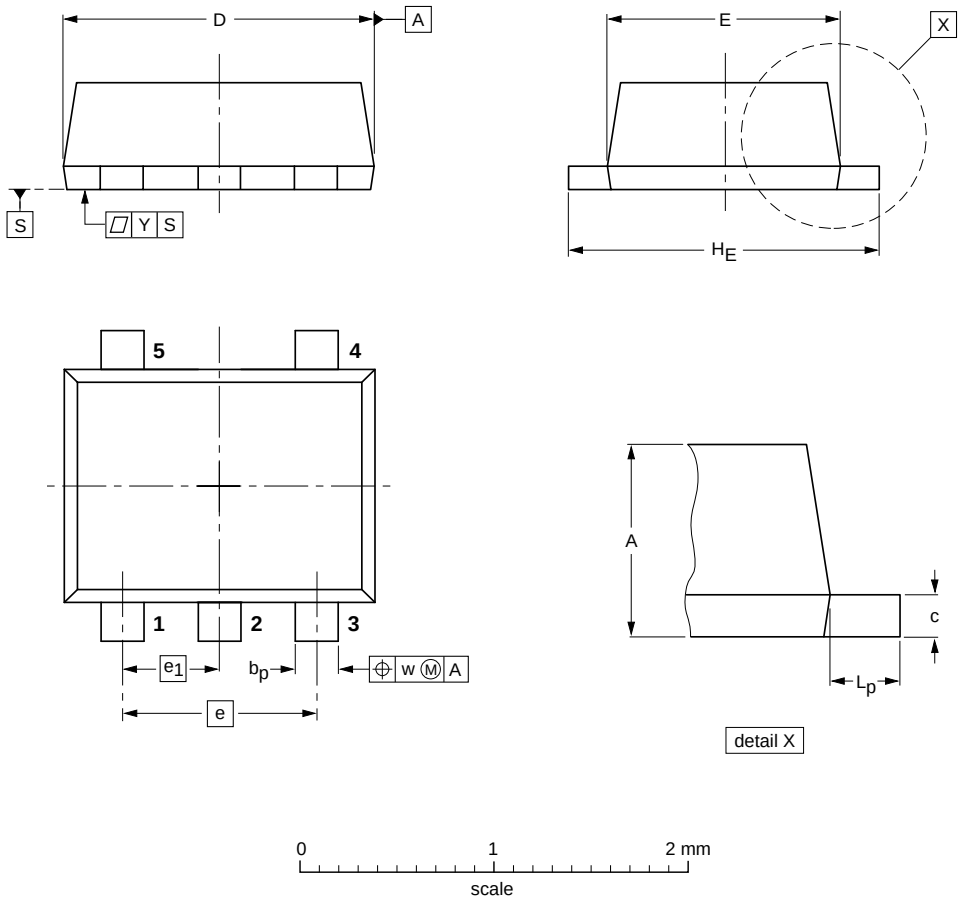
Notes

1. Including plating thickness.
2. Can be visible in some manufacturing processes.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT886		MO-252				~~04-07-15~~ 04-07-22

Fig 8. Package outline PEMI2QFN (SOT886/XSON6)

Plastic surface-mounted package; 5 leads **SOT665**



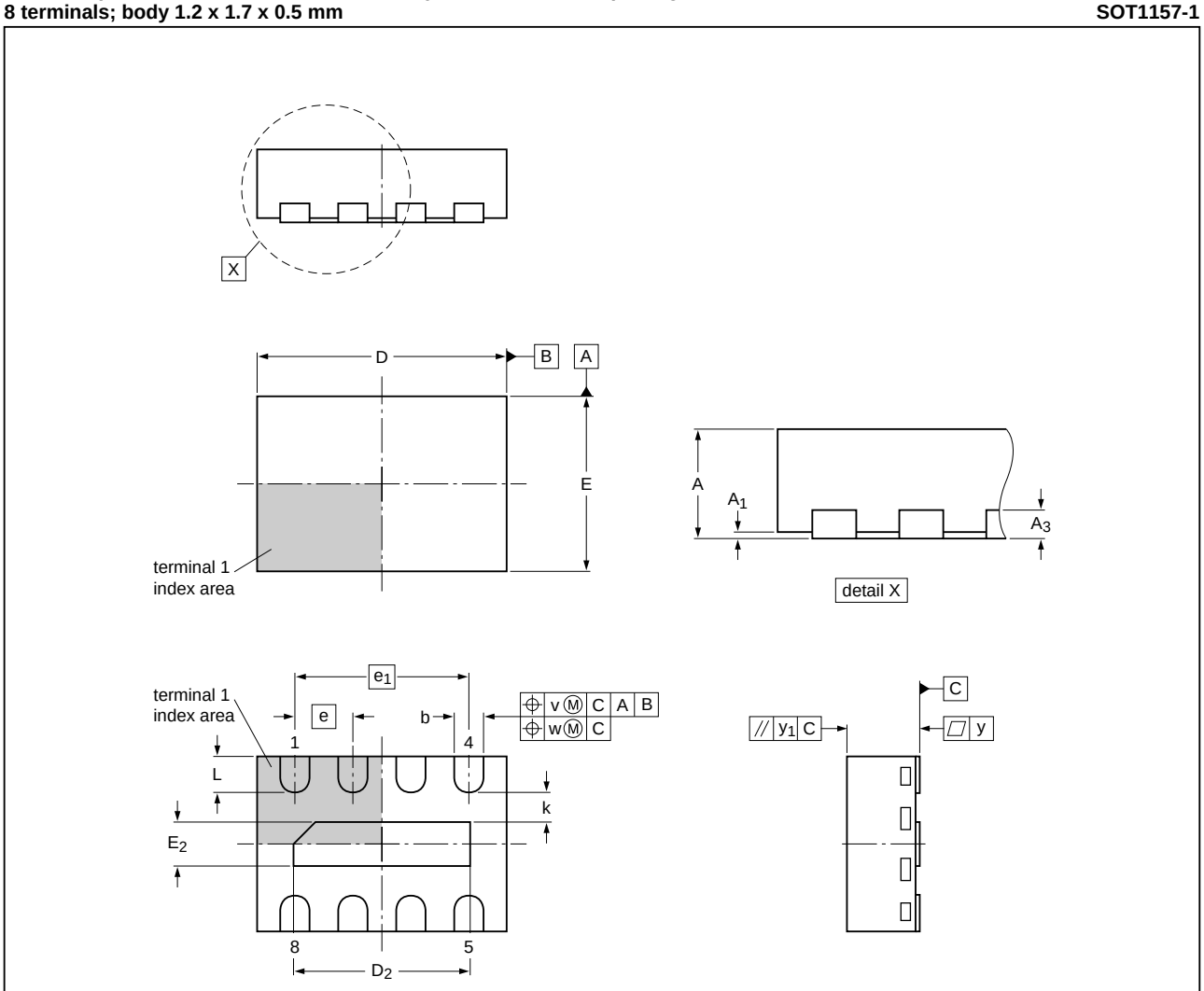
DIMENSIONS (mm are the original dimensions)

UNIT	A	b_p	c	D	E	e	e_1	H_E	L_p	w	y
mm	0.6 0.5	0.27 0.17	0.18 0.08	1.7 1.5	1.3 1.1	1.0	0.5	1.7 1.5	0.3 0.1	0.1	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT665						~~04-11-08~~ 06-03-16

Fig 9. Package outline PEMI2STD (SOT665)

HXSON8: plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.7 x 0.5 mm **SOT1157-1**



Dimensions

Unit(1)		A	A_1	A_3	b	D	D_2	E	E_2	e	e_1	k	L	v	w	y	y_1
mm	max	0.5	0.05		0.25	1.8	1.25	1.3	0.35				0.30				
	nom			0.127	0.20	1.7	1.20	1.2	0.30	0.4	1.2	0.2	0.25	0.1	0.05	0.05	0.05
	min		0.00		0.15	1.6	1.15	1.1	0.25				0.20				

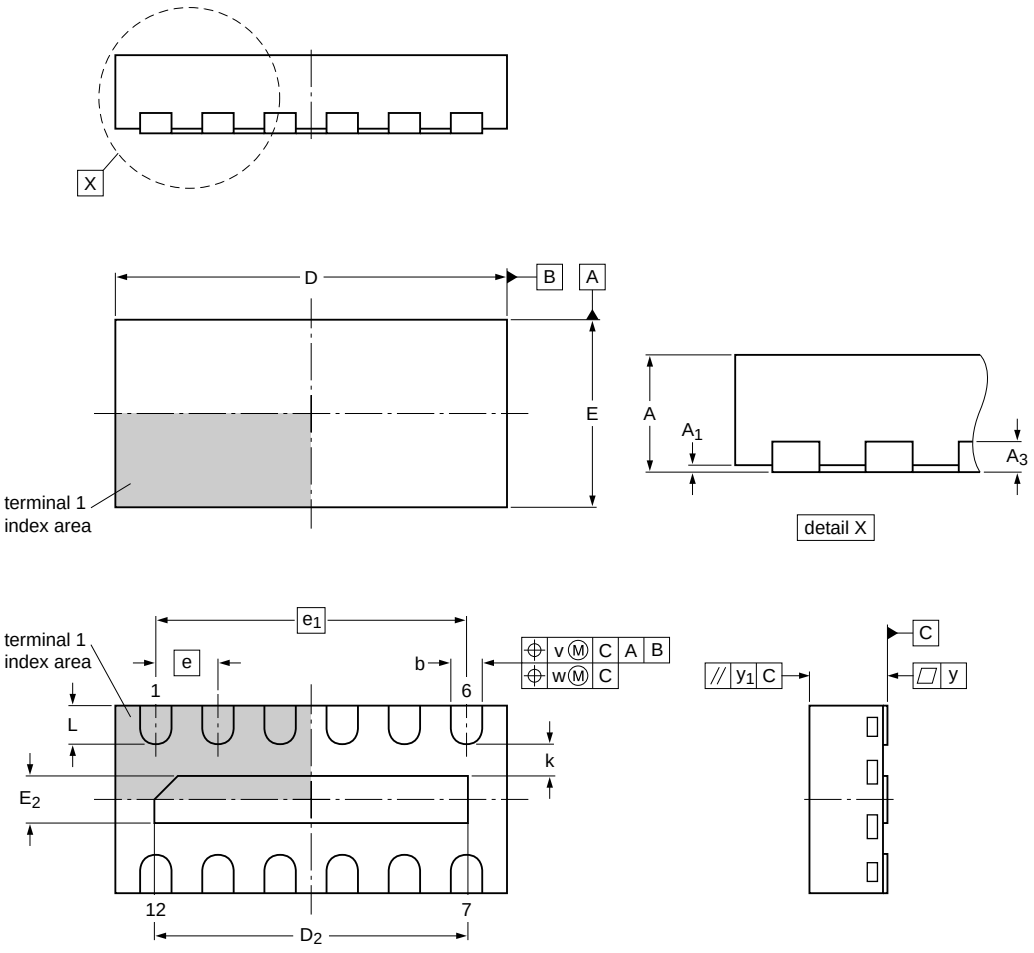
Note
1. Plastic or metal protrusions of 0.075 maximum per side are not included.

sot1157-1_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1157-1	- - -	- - -	- - -			~~09-12-16~~ 09-12-17

Fig 10. Package outline PEMI4QFN (SOT1157-1/HXSON8)

HXSON12: plastic thermal enhanced extremely thin small outline package; no leads; 12 terminals; body 1.2 x 2.5 x 0.5 mm **SOT1158-1**



Dimensions

Unit[1]		A	A_1	A_3	b	D	D_2	E	E_2	e	e_1	k	L	v	w	y	y_1
	max	0.5	0.05		0.25	2.6	2.1	1.3	0.35				0.30				
mm	nom			0.127	0.20	2.5	2.0	1.2	0.30	0.4	2	0.2	0.25	0.1	0.05	0.05	0.05
	min		0.00		0.15	2.4	1.9	1.1	0.25				0.20				

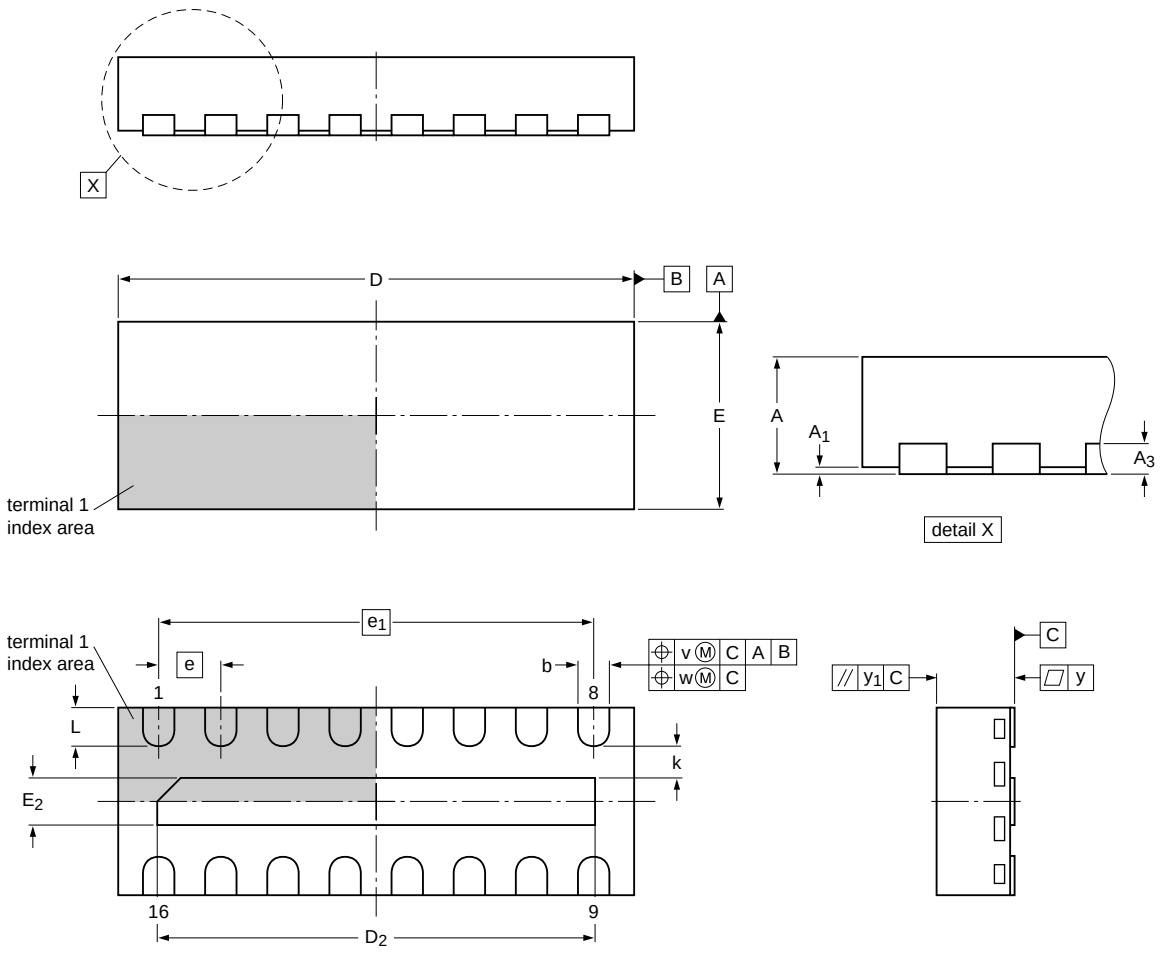
Note
1. Plastic or metal protrusions of 0.075 maximum per side are not included.

sot1158-1_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1158-1	- - -	- - -	- - -			~~09-12-16~~ 09-12-17

Fig 11. Package outline PEMI6QFN (SOT1158-1/HXSON12)

HXSON16: plastic thermal enhanced extremely thin small outline package; no leads; 16 terminals; body 1.2 x 3.3 x 0.5 mm **SOT1159-1**



Dimensions

Unit(1)		A	A_1	A_3	b	D	D_2	E	E_2	e	e_1	k	L	v	w	y	y_1
	max	0.5	0.05		0.25	3.4	2.9	1.3	0.35				0.30				
mm	nom			0.127	0.20	3.3	2.8	1.2	0.30	0.4	2.8	0.2	0.25	0.1	0.05	0.05	0.05
	min		0.00		0.15	3.2	2.7	1.1	0.25				0.20				

Note

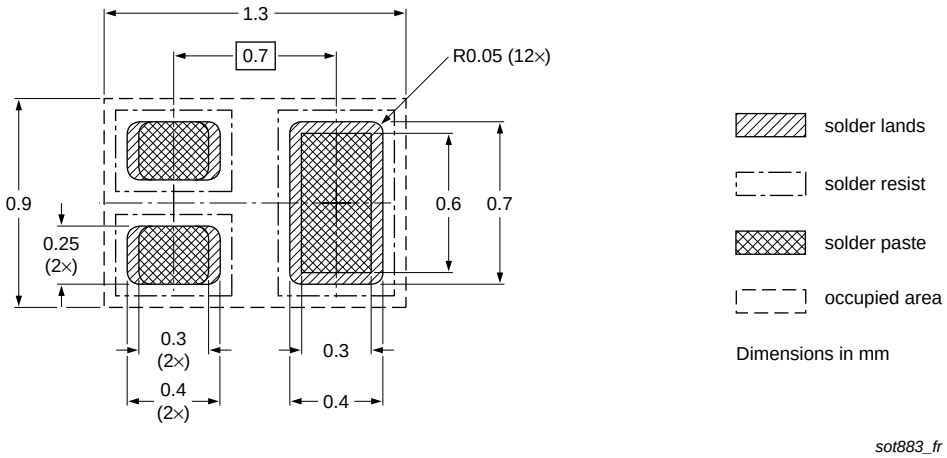
1. Plastic or metal protrusions of 0.075 maximum per side are not included.

sot1159-1_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1159-1	- - -	- - -	- - -			~~09-12-16~~ 09-12-17

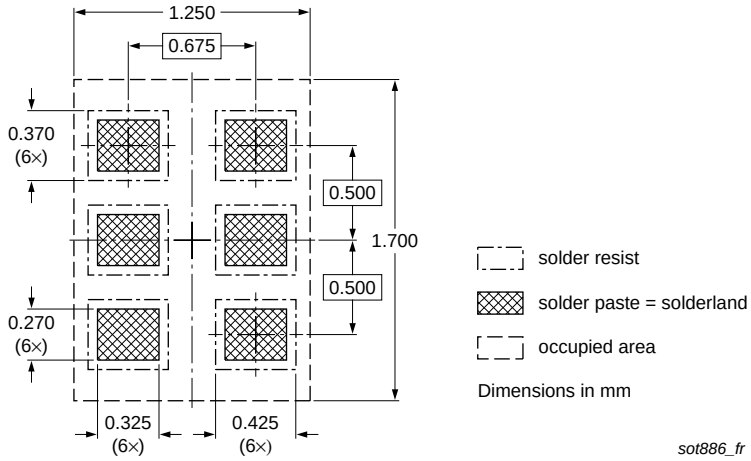
Fig 12. Package outline PEMI8QFN (SOT1159-1/HXSON16)

9. Soldering



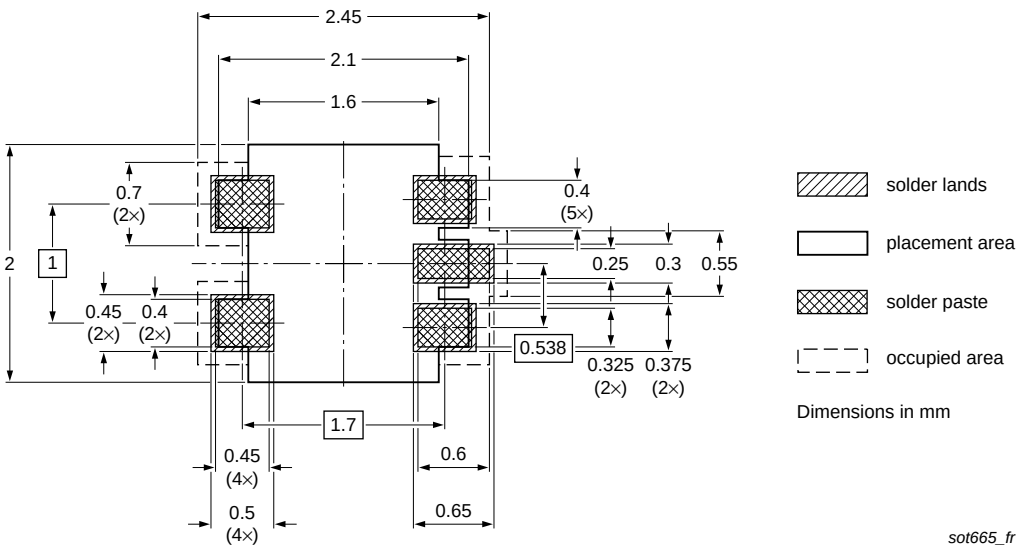
Reflow soldering is the only recommended soldering method.

Fig 13. Reflow soldering PEMI1QFN (SOT883/SC-101)



Reflow soldering is the only recommended soldering method.

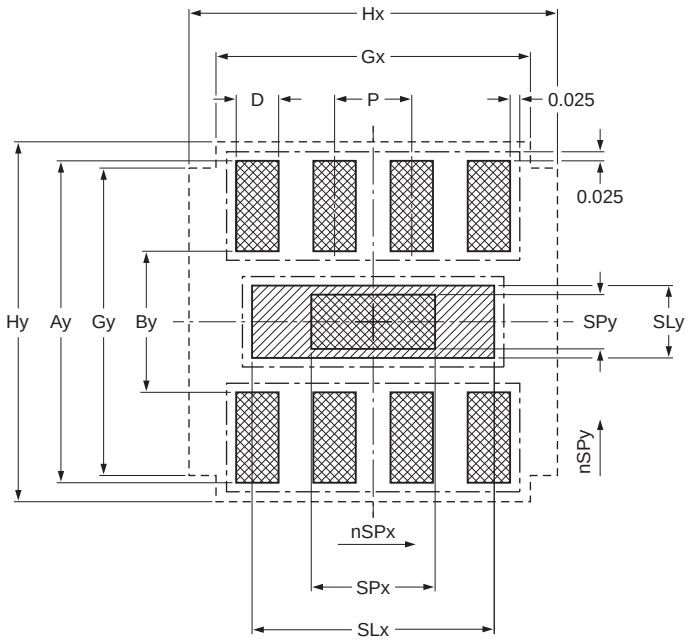
Fig 14. Reflow soldering PEMI2QFN (SOT886/XSON6)



Reflow soldering is the only recommended soldering method.

Fig 15. Reflow soldering PEMI2STD (SOT665)

Footprint information for reflow soldering of HXSON8 package **SOT1157-1**



Generic footprint pattern
Refer to the package outline drawing for actual layout

solder land

solder paste deposit

solder land plus solder paste

occupied area

solder resist

DIMENSIONS in mm

P	Ay	By	D	Slx	Sly	SPx	SPy	Gx	Gy	Hx	Hy
0.40	1.75	0.75	0.22	1.25	0.35	0.6	0.2	1.65	1.45	1.95	2.0

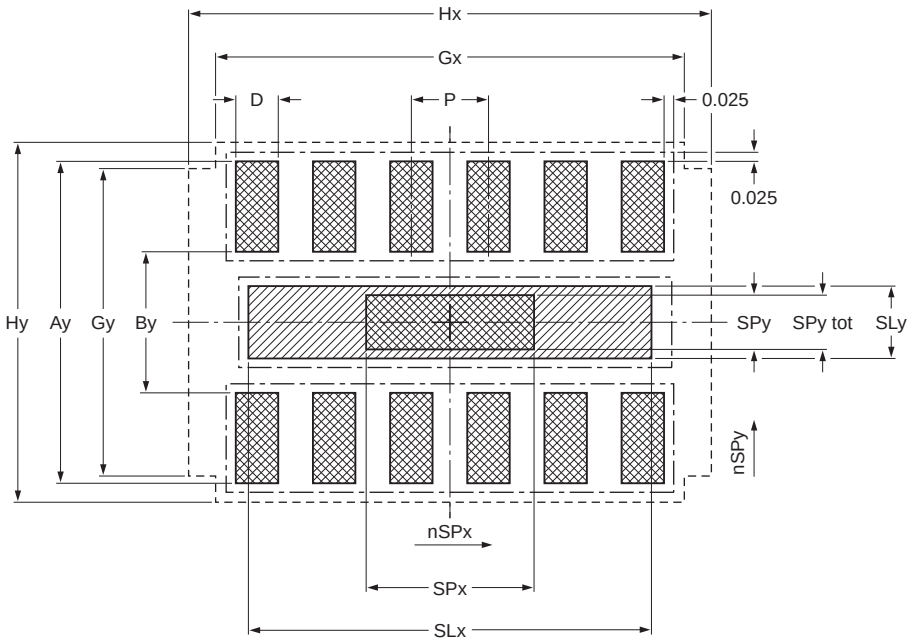
Issue date ~~11-06-27~~ 11-07-06

sot1157-1_fr

Reflow soldering is the only recommended soldering method.

Fig 16. Reflow soldering PEMI4QFN (SOT1157-1/HXSON8)

Footprint information for reflow soldering of HXSON12 package **SOT1158-1**



Generic footprint pattern
Refer to the package outline drawing for actual layout

solder land

solder paste deposit

solder land plus solder paste

occupied area

solder resist

DIMENSIONS in mm

P	Ay	By	D	Slx	Sly	SPx	SPy	Gx	Gy	Hx	Hy
0.40	1.75	0.75	0.22	2.1	0.35	0.9	0.2	2.45	1.45	2.75	2.0

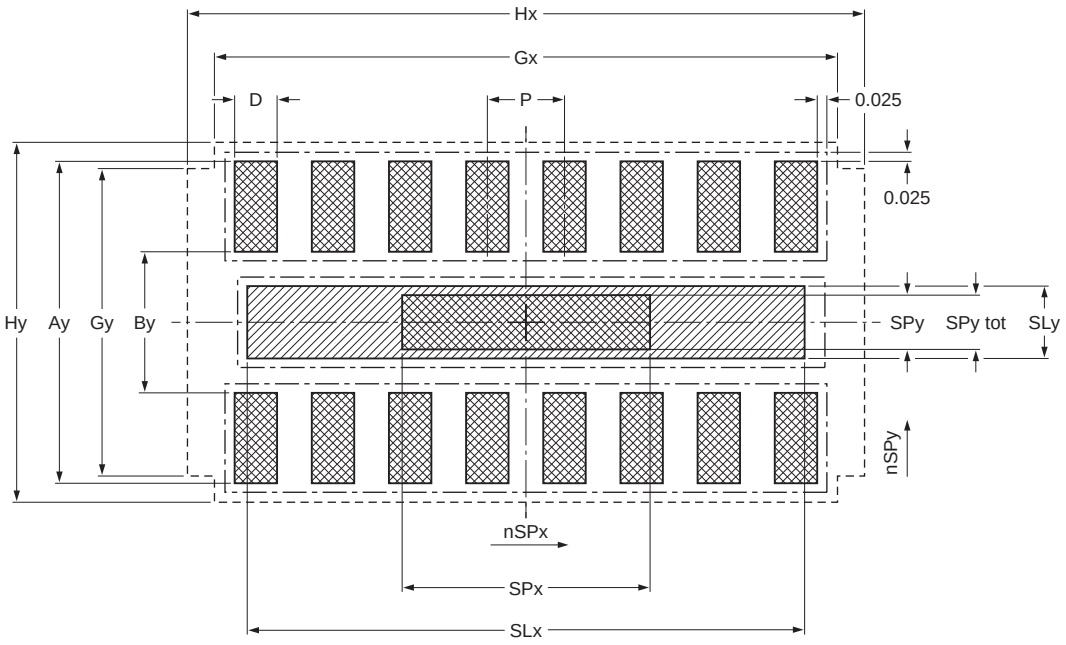
Issue date ~~11-06-27~~ 11-07-06

sot1158-1_fr

Reflow soldering is the only recommended soldering method.

Fig 17. Reflow soldering PEMI6QFN (SOT1158-1/HXSON12)

Footprint information for reflow soldering of HXSON16 package **SOT1159-1**



Generic footprint pattern
Refer to the package outline drawing for actual layout

solder land

solder paste deposit

solder land plus solder paste

occupied area

solder resist

DIMENSIONS in mm

P	Ay	By	D	Slx	Sly	SPx	SPy	Gx	Gy	Hx	Hy
0.40	2.15	0.75	0.21	2.9	0.35	1.3	0.2	3.25	1.45	3.55	2.4

Issue date ~~11-06-27~~ 11-07-06

sot1159-1_fr

Reflow soldering is the only recommended soldering method.

Fig 18. Reflow soldering PEMI8QFN (SOT1159-1/HXSON16)

10. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PEMIXQFN_PEMI2STD_FAM v.2	20111103	Product data sheet	-	PEMIXQFN_PEMI2STD_FAM v.1
Modifications:	• Table 3 “Pinning”: corrected pinning description for PEMI8QFN (SOT1159-1); updated simplified outline of SOT886 • Section 11 “Legal information”: updated			
PEMIXQFN_PEMI2STD_FAM v.1	20110729	Product data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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13. Contents

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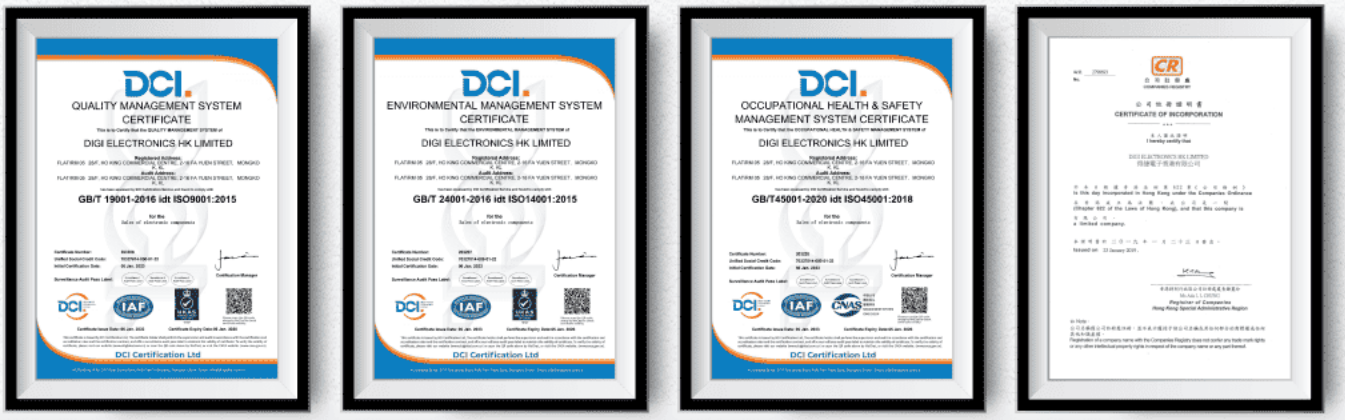

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